NSN 5961-01-565-2170

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-565-2170 **Inclosure Material:** Glass **Overall Length:** Between 0.120 inches and 0.300 inches **Overall Diameter:** Between 0.060 inches and 0.107 inches **Mounting Facility Quantity:** 2 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 forward voltage, peak **Current Rating Per Characteristic:** 4.70 milliamperes forward current, nonrepetitive, peak total value torr **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli